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Interfacial Systems Chemistry: Out of the Vacuum, Through the Liquid, Into the Cell

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Interfacial systems chemistry: out of the vacuum—through the liquid—into the cell

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Is there a Au–S bond dipole in self-assembled monolayers on gold?†

LinJun Wang,^{ac} Gerold M. Rangger,^b ZhongYun Ma,^c QiKai Li,^c Zhigang Shuai,*^{ac} Egbert Zojer*^b and Georg Heimel^d

Received 18th November 2009, Accepted 8th February 2010 First published as an Advance Article on the web 24th February 2010 DOI: 10.1039/b924306m

Self-assembled monolayers (SAMs) of functionalized thiols are widely used in organic (opto)electronic devices to tune the work function, Φ , of noble-metal electrodes and, thereby, to optimize the barriers for charge-carrier injection. The achievable Φ values not only depend on the intrinsic molecular dipole moment of the thiols but, importantly, also on the bond dipole at the Au–S interface. Here, on the basis of extensive density-functional theory calculations, we clarify the ongoing controversy regarding the existence, the magnitude, and the nature of that bond dipole.

The work function, Φ , of a metal is defined as the energy difference between its Fermi level, $E_{\rm F}$, and the energy of an electron at rest directly outside the metal surface, $E_{\rm vac}$. Thus, to modify Φ by an amount $\Delta \Phi$, a SAM must introduce a potential energy step between metal and vacuum. To allow for the rational design of molecules that induce a desired $\Delta \Phi$, the latter is commonly split into two additive components. The first, $\Delta E_{\rm vac}$, arises from the molecular ad-layer only and the second, $\Delta E_{\rm BD}$, reflects the interfacial charge rearrangements upon molecule–metal bonding. Disregarding atomic-scale lateral inhomogeneities in the SAM, each potential energy step is linked to a corresponding plane-averaged charge (re)distribution, $\rho(z)$, via the Poisson equation,^{1–3}

$$\nabla^2 E(z) = \frac{e}{\varepsilon_0} \rho(z) \tag{1}$$

where *e* denotes the (by definition positive) elementary charge and ε_0 the vacuum permittivity. As only a net dipole moment perpendicular to the surface leads to a non-vanishing ΔE , eqn (1) is commonly replaced by the heuristic Helmholtz equation, where the two contributions to $\Delta \Phi$ are regarded as arising from two laterally homogenous dipole layers.^{1–9}

$$\Delta \Phi = \Delta E_{\rm vac} + \Delta E_{\rm BD} = -\frac{en}{\varepsilon_0} \left[\frac{|\mu| \cos(\beta)}{\varepsilon_{\rm eff}(n)} + \mu_{\rm BD}(n) \right]$$
(2)

^h Institute of Solid State Physics, Graz University of Technology, Petersgasse 16, A-8010 Graz, Austria. E-mail: egbert.zojer@tugraz.at; Fax: +43/(0)316/873-8466; Tel: +43/(0)316/873-8475 Here, *n* denotes the molecular packing density, $|\mu|$ is the dipole moment of the free molecule, and β is the angle between the dipole axes of the molecules in the SAM and the surface normal. Generally, the depolarization factor ε_{eff} and the *bond dipole* at the Au–S interface, μ_{BD} , depend on the coverage in a non-trivial manner,¹⁰ but the same *n* (full coverage) is assumed for all SAMs considered here.

For many adsorbates, the conceptual partitioning of $\Delta \Phi$ into a purely molecular part (first term in eqn (2)) and a bonding-induced part (second term in eqn (2)) is unambiguously defined.² However, for SAMs formed by thiols, two different partitioning schemes appear in the literature. For the molecular contribution to $\Delta \Phi$, thiols (*i.e.*, R–SH species) are considered in the first^{1–5} and R–S[•] radical species in the second.^{6–9} These correspond to two conceptually different points of view,

$$R-SH + Au \rightarrow R-S-Au + 1/2H_2$$
 (3a)

$$R-S^{\bullet} + Au \rightarrow R-S-Au \tag{3b}$$

where the first regards the bonding of the SAM to the metal as *replacing* S–H bonds with S–Au bonds and the second as *forming* new bonds between R–S[•] radicals and gold. Naturally, appreciably different molecular dipole moments are found for the saturated and the radical species and, consequently, by virtue of eqn (2), also different ΔE_{vac} values (see ESI†). As, however, the final situation is identical in both approaches, *i.e.*, a thiolate SAM on a gold surface (R–S–Au) with one given $\Delta \Phi$, eqn (2) implies that then also the bonding-induced contribution to the work-function modification, ΔE_{BD} , must differ between the two approaches. In density-functional theory (DFT) calculations, the latter is obtained by applying eqn (1) to the plane-averaged charge-density differences, ρ_{diff} , that are associated with the processes indicated in eqn (3).^{1–3,9}

$$\rho_{\rm diff}^{\rm sat} = \rho_{\rm sys} - \rho_{\rm Au} - (\rho_{\rm sat} - \rho_{\rm H}) \tag{4a}$$

$$\rho_{\rm diff}^{\rm rad} = \rho_{\rm sys} - \rho_{\rm Au} - \rho_{\rm rad} \tag{4b}$$

Here, the subscripts sys, Au, rad, sat, and H refer to the entire metal/SAM system, the pristine metal, the free-standing molecular monolayer of radical and H-saturated species, and the layer of saturating H-atoms, respectively. Experimentally, $\Delta E_{\rm BD}$ can be extracted from $\Delta \Phi$ measurements on a series of molecules with the aid of their calculated dipole moments and reasonable estimates for all other quantities in eqn (2).⁴⁻⁷

Notably, DFT calculations pursuing the *saturated* approach have found values of $\Delta E_{\rm BD} \approx -1.2$ eV for SAMs of biphenylthiols on Au(111),¹⁻³ while negligible values (-0.01 - 0.08 eV)

^a Department of Chemistry, Tsinghua University, 100084 Beijing, PR China. E-mail: zgshuai@tsinghua.edu.cn; Fax: +86/10/6279-7689; Tel: +86/10/6279-7689

^c Key Laboratory of Organic Solids, Beijing National Laboratory for Molecular Sciences (BNLMS), Institute of Chemistry,

Chinese Academy of Sciences, 100190 Beijing, PR China

^d Institut für Physik, Humboldt-Universität zu Berlin, Newtonstr. 15, D-12489 Berlin, Germany

[†] Electronic supplementary information (ESI) available: Computational methodology and additional computational results on the properties of the free-standing molecular monolayers. See DOI: 10.1039/b924306m

have been reported for SAMs of alkylthiols following the radical scheme.⁹ Even more strikingly, experimental studies on thiols with an aromatic ring adjacent to the -SH group have reported a ΔE_{BD} of -0.85 eV when relying on μ values calculated for *saturated* molecules,⁵ while a ΔE_{BD} between +0.6 and +1.0 eV has been found using μ values calculated for radicals.⁶ Thus, the bond dipole of thiols on gold appears to depend not only on the chemical structure of the molecular backbone but, rather unsatisfactorily, also on the chosen partitioning scheme. It is the purpose of the latter, however, to permit correlating the chemical structure of the SAMforming molecules with the achievable $\Delta \Phi$, thus allowing for the rational design of suitable molecules. Therefore, the question arises which of the two possibilities is better suited to provide a chemically and physically insightful picture of the relevant interfacial processes.

To elucidate this question, we performed slab-type DFT band-structure calculations for a series of functionalized thiols on Au(111) using VASP,¹¹ the internal-coordinate geometry optimizer GADGET,¹² and XCRYSDEN¹³ (for details see ESI[†]). As shown in Fig. 1a, each molecule is endowed with a strongly polar head-group substitution that either lowers Φ in the case of the electron-donating amino group $(-NH_2)$ or increases Φ in the case of the electron-accepting cyano group (-CN);¹⁴ note that the total dipole moments of these molecules are composed of the contributions from the head groups on one side and from the thiol groups on the other side, the latter pointing roughly in the direction of the S-H bonds (vide infra). An in-depth analysis of the electronic properties of the molecules shown in Fig. 1a as well as the corresponding SAMs is provided in ref. 14. For the sake of comparability, the same rectangular $p(\sqrt{3} \times 3)$ unit cell containing two molecules is assumed for all monolayers (Fig. 1b). To individually access all components in eqn (4), separate calculations were performed on the corresponding sub-systems listed there.

As it appears more natural and chemically intuitive (in contrast to R-S[•] radicals, the -SH terminated molecules are readily accessible to experiment), the saturated scenario is discussed first. There, when setting up the system for the free-standing molecular monolayer in order to determine $\Delta E_{\rm vac}$ in eqn (2) and $\rho_{\rm sat}$ in eqn (4a), one is faced with the choice of where to place the hydrogen atom relative to the sulfur (Fig. 1c). Two positions can be identified, where the hydrogen lies in the plane defined by the sulfur and the two nearest carbon atoms. As the S-C bond is inclined to the surface normal by $> 17^{\circ}$ for all investigated molecules and the C–S–H bond angle is only $\sim 97^{\circ}$, this results in the hydrogens to lie above the plane of the sulfur atoms in position II (*i.e.*, farther away from where the metal surface will be located once bonding is established), and below the sulfur plane in position I. As ΔE_{BD} clearly should reflect the bonding of sulfur to gold, the latter position is obviously a better choice; one is primarily interested in the interfacial charge rearrangements between sulfur and gold and not in some spatial region within the molecular ad-layer, i.e., where the saturating hydrogen atoms are located in position II (Fig. 1c). The $\Delta E_{\rm BD}$ values obtained with the hydrogen at position I in the free-standing thiol layer are listed in Table 1. They are all negative and they reflect the local polarisability¹⁴ of the molecular backbone



Fig. 1 (a) Chemical structures and labels of the investigated thiols; X stands for amino ($-NH_2$) and cyano (-CN) head-group substitutions. (b) Top view of the $p(\sqrt{3} \times 3)$ surface unit cell containing two molecules (shown for C1), which is assumed for all SAMs. (c) Side view of one NH₂-substituted C1 molecule in the free-standing H-saturated monolayer indicating the two possible hydrogen positions, the inclination of the S–C bond to the surface normal, and the height difference, $\Delta z_{1,2}$, between the two saturating hydrogen atoms in position I and II.

adjacent to the sulfur to some extent, *i.e.*, larger values are observed for more polarisable backbones.¹⁴ Notably, the value for the alkyl backbone C1 is non-zero. Also listed are the $\Delta E_{\rm BD}$ values for hydrogen position II. Not only are they markedly different, but closer inspection of Table 1 reveals that the difference to the H-position I values increases essentially linearly with the height difference, $\Delta z_{1,2}$, between the hydrogens in the two positions (Fig. 1c), *i.e.*, with the projection of the local dipole moment around the –SH group onto the surface normal (*vide supra*); the corresponding plot is shown in Fig. 2.‡ This indicates that, using the saturated partitioning scheme, $\Delta E_{\rm BD}$ also reflects the position of the saturated plane with respect to the surface normal (Fig. 1c).

To further test the ability of the saturated approach to provide chemically and physically insightful information, we also examined a different quantity, namely the "left-sided" ionisation potentials (IPs) of the free-standing saturated monolayers, which are defined as the energy difference between its highest occupied π -states (the highest fully delocalized σ -states in the case of C1)¹⁴ and E_{vac} on the thiol side;¹⁻³ as the latter obviously differs from E_{vac} above the head-group substituents by ΔE_{vac} , also the "right-sided" IPs must differ from their left-sided counterparts by ΔE_{vac} .¹⁻³



Fig. 2 Difference between the ΔE_{BD} values obtained with the saturated partitioning scheme for hydrogen positions I and II as a function of $\Delta z_{1,2}$, the height difference between the saturating hydrogen atoms in position I and II;[†] the dashed line is a linear fit through the origin.

Table 1 DFT-calculated vertical distance, $\Delta z_{1,2}$, between the saturating hydrogen atoms in positions I and II,‡ left-sided ionisation potential, IP_{left}, energy perturbation of the highest occupied delocalized orbitals upon metal–molecule bonding, $E_{\rm corr}$, and potential energy step due to the bond dipole, $\Delta E_{\rm BD}$, for hydrogen position I as well as $\Delta E_{\rm BD}$ for hydrogen position II obtained for the saturated partitioning scheme

| | | H-Position | | | | |
|--------------------|-----------------------------|---------------------------|-------------------------|--------------------------|----------------------------|--|
| | | Ι | | | II | |
| System | $\Delta z_{1,2}/\text{\AA}$ | $\overline{IP_{left}/eV}$ | $E_{\rm corr}/{\rm eV}$ | $\Delta E_{ m BD}/ m eV$ | $\Delta E_{ m BD}/{ m eV}$ | |
| C1-NH ₂ | 1.919 | 7.74 | 0.03 | -1.27 | 0.16 | |
| C1–CN | 1.880 | 8.17 | -0.01 | -1.00 | 0.13 | |
| C2–NH ₂ | 0.675 | 5.03 | 0.14 | -1.14 | -0.69 | |
| C2–CN | 0.515 | 5.13 | 0.17 | -1.20 | -0.85 | |
| C3–NH ₂ | 1.894 | 3.89 | 0.16 | -1.87 | -0.78 | |
| C3–CN | 2.067 | 3.74 | 0.16 | -2.06 | -0.88 | |
| T1-NH ₂ | 0.821 | 4.26 | 0.14 | -1.54 | -1.01 | |
| T1–CN | 0.788 | 4.30 | 0.14 | -1.57 | -1.07 | |
| $T2-NH_2$ | 1.269 | 4.04 | 0.12 | -1.70 | -0.94 | |
| T2–CN | 1.266 | 4.10 | 0.13 | -1.71 | -0.95 | |
| T3-NH ₂ | 1.173 | 3.99 | 0.13 | -1.70 | -0.98 | |
| T3–CN ² | 1.160 | 4.01 | 0.13 | -1.72 | -1.02 | |

of the molecular backbones, *i.e.*, lower values are found for structures with a more extended conjugation.¹⁴ Similarly to $\Delta E_{\rm BD}$, IP_{left} also reflects the orientation of the S–C bond or, more precisely, the projection of the local dipole moment of the –SH group onto the layer normal (see ESI[†]).

Finally, it has been observed that the right-sided IPs in the free-standing monolayers differ from the IP of the SAM bonded to the metal (reported in ref. 14) by a small amount, $E_{\rm corr}$, which reflects the perturbation of the molecular electronic structure through metal-molecule bonding.¹⁻³ As shown in Table 1, these $E_{\rm corr}$ values are below 0.2 eV for all investigated systems. This underlines that replacing the S-H bonds with S-Au bonds has little effect on the energy levels in the SAM and, again, the saturated partitioning scheme is seen to conserve the chemical information on the nature of the molecular backbone.

We now turn to the radical scenario where, instead of *replacing* S–H bonds with S–Au bonds, a new bond is *formed* between the $R-S^{\bullet}$ species and the gold surface. While the radical is unlikely to actually participate in the process of

Table 2 DFT-calculated potential energy step due to the bond dipole, $\Delta E_{\rm BD}$, left-sided ionisation potential, IP_{left}, and energy perturbation of the highest occupied delocalized orbitals upon metal–molecule bonding, $E_{\rm corr}$, obtained for the radical partitioning scheme

| System | $\Delta E_{ m BD}/{ m eV}$ | IP_{left}/eV | $E_{\rm corr}/{ m eV}$ |
|--------------------|----------------------------|----------------|------------------------|
| C1–NH ₂ | -0.04 | 8.95 | -0.02 |
| C1–CN | -0.04 | 9.07 | -0.09 |
| C2-NH ₂ | 1.11 | 6.07 | -1.11 |
| C2–CN | 0.96 | 6.08 | -1.08 |
| C3–NH ₂ | 1.33 | 6.11 | -0.86 |
| C3–CN | 1.28 | 6.14 | -0.83 |
| T1-NH ₂ | 1.28 | 5.89 | -1.11 |
| T1–CN | 1.19 | 5.88 | -1.07 |
| $T2-NH_2$ | 1.22 | 5.81 | -1.07 |
| T2–CN | 1.17 | 5.81 | -1.08 |
| T3-NH ₂ | 1.27 | 5.89 | -0.99 |
| T3–CN | 1.23 | 5.89 | -0.99 |

SAM formation, one obviously needs not be concerned with the position of a saturating hydrogen atom on the sulfur. The results obtained with the radical partitioning scheme are listed in Table 2. In agreement with previous studies following this approach,⁹ a vanishing ΔE_{BD} is found for the alkyl backbone C1 and, for all other molecular structures, ΔE_{BD} changes sign compared to the saturated scheme (Table 1); a potential dependence on the orientation of the S-C bond is hard to assess. Notably, the IP_{left} values in the radical case (Table 2) all lie within the narrow range of 5.8 - 6.1 eV (cf. ref. 8); the exception is again C1 due to the different nature (σ -orbital vs. π -orbital) of the highest occupied delocalized states.¹⁴ Additionally, the $E_{\rm corr}$ values are on the order of 1 eV, yet again with the exception of C1 (vide infra). This leads to the conclusions that, in the radical partitioning scheme, chemical information on the nature of the backbone is largely lost and that the electronic structure of the free-standing radical layer is significantly perturbed upon bonding to the metal.

The reason for these observations is that the radical character of the -S• termination dominates the electronic structure of the free-standing monolayer on the docking-group side and, consequently, also the interfacial charge redistributions upon metal-molecule bond formation. Removing the hydrogen from the sulfur in the thiol and, thus, converting the closedshell molecule into a radical, induces major charge rearrangements on that side of the molecule. The latter can be expressed as $(\rho_{\rm rad} + \rho_{\rm H}) - \rho_{\rm sat}$ and are shown in the left panels of Fig. 3. For all conjugated systems (C2 - T3), the charge redistributions resulting from hydrogen removal reach far onto the molecular backbones, as the sulfur is strongly coupled to their π -electron system. A qualitatively different behaviour is observed in the case of the alkylthiol (C1), where both the π -system and the radical character are strongly localized on the sulfur alone and, therefore, the delocalized σ -states are hardly affected by radical formation. When the bonds between radicals and gold are formed, *i.e.*, when charges are shifted according to eqn (4b), the molecule is essentially converted back to a closed-shell species and the aforementioned charge redistributions are largely reversed in the spatial region of the SAM (left panels in Fig. 3), but not quite. The actual chemical and physical information regarding the Au-S bonding lies hidden in the difference between the processes of removing the hydrogen atoms from the sulfur and "adding" the gold surface



Fig. 3 Left panels: plane-integrated charge-density difference per unit-cell area, $(\rho_{rad} + \rho_H) - \rho_{sat}$, describing the removal of the hydrogen from the thiol (grey) and plane-integrated charge-density difference per unit-cell area, ρ_{diff} after eqn (4b), describing the bond formation between radical and metal (black). Right panels: plane-integrated charge-density difference per unit-cell area, ρ_{diff} after eqn (4a), describing the bonding of the hydrogen-saturated molecular monolayer to the metal. The curves in the right panels, which describe the actual bonding-induced interfacial charge rearrangements, are also the sum of the two curves in the left panel. The vertical lines indicate the (average) positions of the top-most gold layer and the sulfur atoms.

instead. Exactly this difference (right panels in Fig. 3), which actually corresponds to ρ_{diff} in the *saturated* partitioning scheme (eqn (4a)), is obscured in the radical approach.

To summarize, we have identified and discussed two distinctly different ways of defining the Au–S bond dipole in thiol SAMs on Au(111), the saturated and the radical scheme. With a well-defined choice for the positions of the saturating hydrogen atoms on the sulfur, the former conserves information on the chemical structure of the thiols, reflects the orientation of the S–C bond, and provides revealing insights into the interfacial charge rearrangements that occur upon metal-molecule bonding. In particular, a considerable negative $\Delta E_{\rm BD}$ is found for a wide range of molecules, including alkylthiols. On the other hand, when considering unsaturated R-S[•] species as the origin of the molecular contribution to the work-function modification, chemical information on the SAM electronic structure is largely lost and the relevant bonding-related charge redistributions at the metal-molecule interface are not accessible, which clearly renders this second approach less appealing.

This work was supported by the Ministry of Science and Technology of China through the 973 program (Grants 2006CB806200 and 2006CB932100), by the FWF through project P20972-N20, and by the DFG through the Sfb448 "Mesoscopically Organized Composites".

Notes and references

‡ As there are two inequivalent molecules per unit cell (Fig. 1b), the average $\Delta z_{1,2}$ values are reported.

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